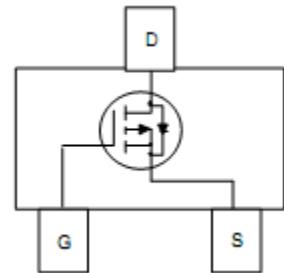


**P-Channel Enhancement-Mode MOSFETs**

SOT-23

**■MAXIMUM RATINGS**

Characteristic	Symbol	Max	Unit
Drain-Source Voltage	$BV_{DSS}$	-30	V
Gate- Source Voltage	$V_{GS}$	$\pm 12$	V
Drain Current (continuous)	$I_D$	-2.6	A
Drain Current (pulsed)	$I_{DM}$	-18	A
Total Device Dissipation $T_A=25^\circ\text{C}$	$P_D$	1000	mW
Junction	$T_J$	150	$^\circ\text{C}$
Storage Temperature	$T_{stg}$	-55 to +150	$^\circ\text{C}$

## ■ ELECTRICAL CHARACTERISTICS

( $T_A=25^\circ\text{C}$  unless otherwise noted  $25^\circ\text{C}$ )

Characteristic	Symbol	Min	Typ	Max	Unit
Drain-Source Breakdown Voltage ( $I_D = -250\mu\text{A}$ , $V_{GS}=0\text{V}$ )	$\text{BV}_{DSS}$	-30	—	—	V
Gate Threshold Voltage ( $I_D = -250\mu\text{A}$ , $V_{GS} = V_{DS}$ )	$V_{GS(\text{th})}$	-1.3	—	-2.3	V
Diode Forward Voltage Drop ( $I_S = -1\text{A}$ , $V_{GS}=0\text{V}$ )	$V_{SD}$	—	—	-1	V
Zero Gate Voltage Drain Current ( $V_{GS}=0\text{V}$ , $V_{DS} = -24\text{V}$ ) ( $V_{GS}=0\text{V}$ , $V_{DS} = -24\text{V}$ , $T_A=55^\circ\text{C}$ )	$I_{DSS}$	—	—	-1 -5	$\mu\text{A}$
Gate Body Leakage ( $V_{GS}=\pm 12\text{V}$ , $V_{DS}=0\text{V}$ )	$I_{GSS}$	—	—	$\pm 100$	nA
Static Drain-Source On-State Resistance ( $I_D = -2.6\text{A}$ , $V_{GS} = -10\text{V}$ )	$R_{DS(\text{ON})}$	—	—	130	$\text{m}\Omega$
Static Drain-Source On-State Resistance ( $I_D = -2\text{A}$ , $V_{GS} = -4.5\text{V}$ )	$R_{DS(\text{ON})}$	—	—	180	$\text{m}\Omega$
Input Capacitance ( $V_{GS}=0\text{V}$ , $V_{DS} = -15\text{V}$ , $f=1\text{MHz}$ )	$C_{ISS}$	—	854	—	pF
Output Capacitance ( $V_{GS}=0\text{V}$ , $V_{DS} = -15\text{V}$ , $f=1\text{MHz}$ )	$C_{OSS}$	—	105	—	pF
Turn-ON Time ( $V_{DS} = -15\text{V}$ , $V_{GS} = -10\text{V}$ , $R_{GEN}=6\Omega$ )	$t_{(\text{on})}$	—	9	—	ns
Turn-OFF Time ( $V_{DS} = -15\text{V}$ , $V_{GS} = -10\text{V}$ , $R_{GEN}=6\Omega$ )	$t_{(\text{off})}$	—	38	—	ns

Pulse Width  $\leq 300 \mu\text{ s}$ ; Duty Cycle  $\leq 2.0\%$

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